

PN200A / MMBT200 PNP General-Purpose Amplifier

Description

This device is designed for general-purpose amplifier applications at collector currents to 300 mA. Sourced from Process 68.



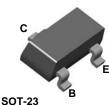


Figure 2. MMBT200 Device Package

Figure 1. PN200A Device Package

Ordering Information

Part Number	Marking	Package	Packing Method	
PN200A	PN200A	TO-92 3L	Bulk	
MMBT200	N2	SOT-23 3L	Tape and Reel	

Absolute Maximum Ratings^{(1),(2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	-45	V
V _{CBO}	Collector-Base Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-6	V
۱ _C	Collector Current - Continuous	-500	mA
T _{J,} T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C.

2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty cycle operations.

Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Ma	Unit	
	Falancie	PN200A ⁽³⁾	MMBT200 ⁽⁴⁾	Onit
P _D	Total Device Dissipation	625	350	mW
	Derate Above 25°C	5.0	2.8	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

Notes:

3. PCB size: FR-4 76 x 114 x 1.57 mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

4. Device mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.

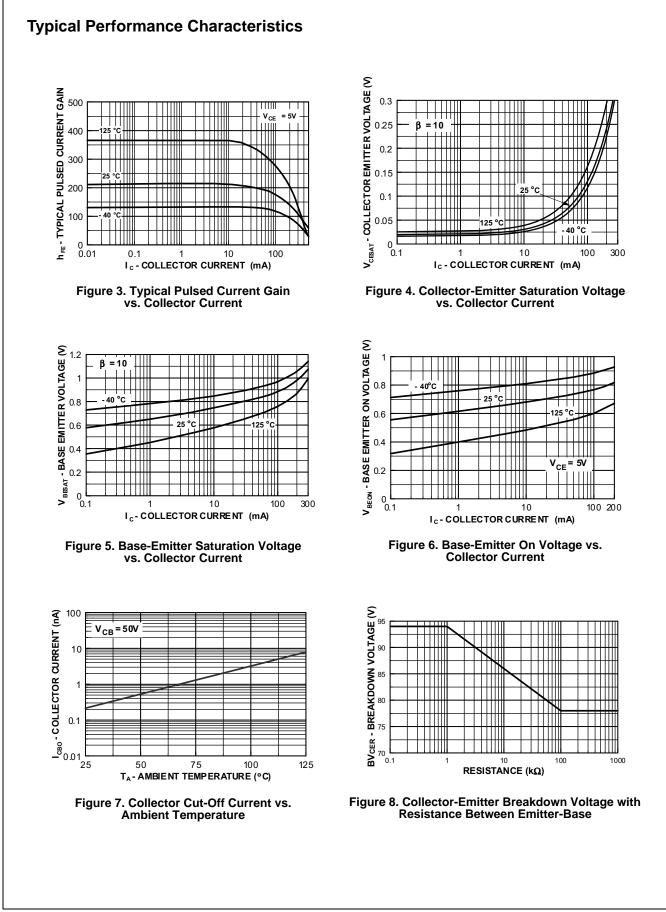
Electrical Characteristics

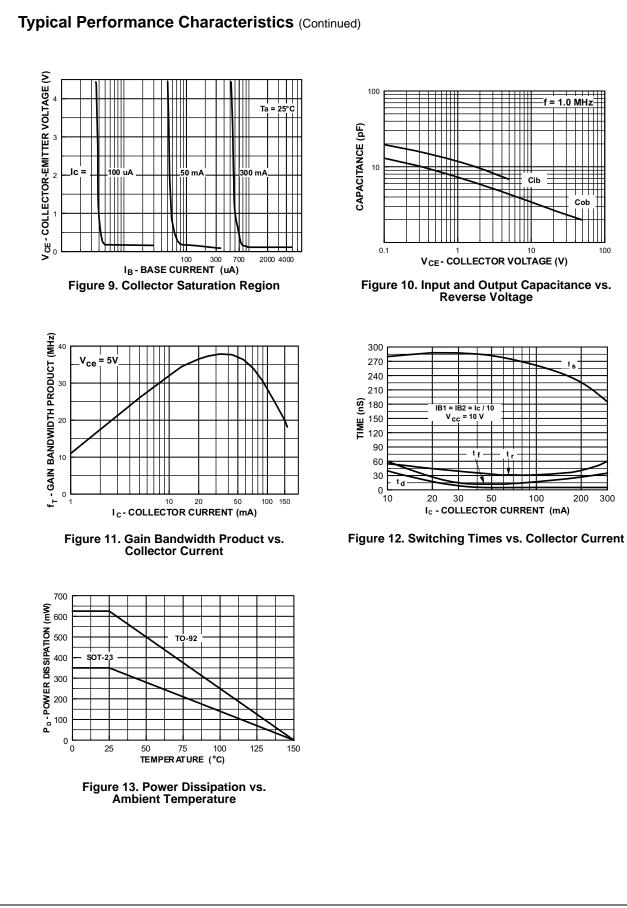
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

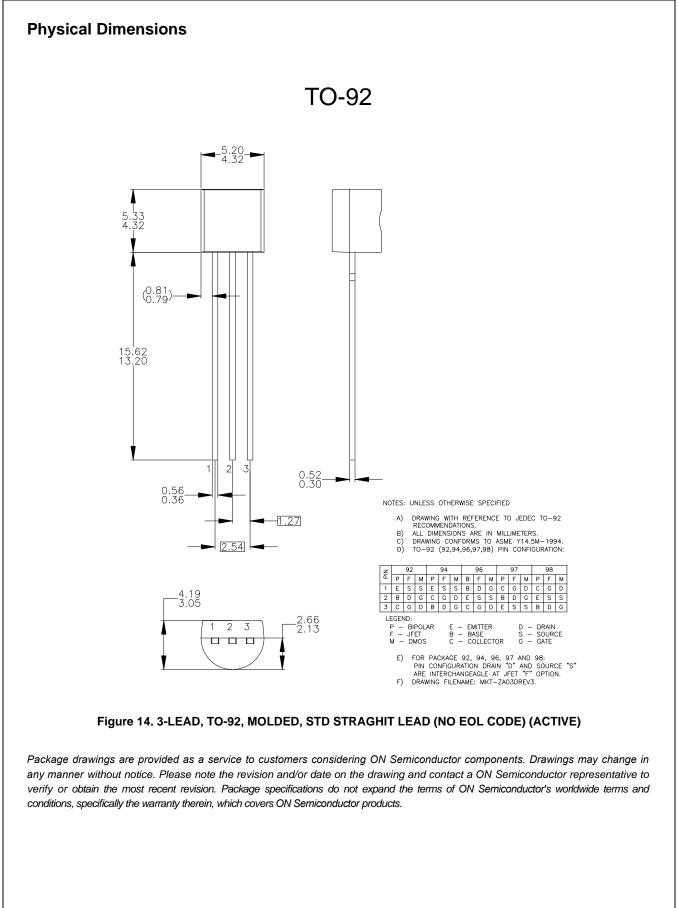
Symbol	Parameter	Conditio	ons	Min.	Max.	Unit
Off Charact	eristics					
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = -10 \ \mu \text{A}, I_{\rm B} = 0$		-60		V
BV_{CEO}	Collector-Emitter Breakdown Voltage ⁽⁵⁾	$I_{\rm C} = -1.0 \text{ mA}, I_{\rm E} = 0$		-45		V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = -10 \ \mu A, \ I_{C} = 0$		-6.0		V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$			-50	nA
I _{CES}	Collector Cut-Off Current	$V_{CE} = -40 \text{ V}, \text{ I}_{E} = 0$			-50	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = -4.0 \text{ V}, I_{C} = 0$			-50	nA
On Charact	eristics					
h _{FE}	DC Current Gain	I _C = -100 μA, V _{CE} = -1.0 V	MMBT200	80		
			PN200A	240		1
		I _C = -10 mA, V _{CE} = -1.0 V	MMBT200	100	450	1
			PN200A	300	600	
		$I_{C} = -100 \text{ mA},$ $V_{CE} = -1.0 \text{ V}^{(5)}$	PN200A	100		
		$I_{\rm C}$ = -150 mA, $V_{\rm CE}$ = -5.0 V ⁽⁵⁾	MMBT200	100	350	
			PN200A	100		
V _{CE} (sat)	Collector-Emitter Saturation	I _C = -10 mA, I _B = -1.0 mA			-0.2	V
	Voltage	$I_{\rm C}$ = -200 mA, $I_{\rm B}$ = -20 mA ⁽⁵⁾			-0.4	v
V (cot)	Base-Emitter Saturation	I _C = -10 mA, I _B = -1.0 mA			-0.85	V
V _{BE} (sat)	Voltage	$I_{\rm C}$ = -200 mA, $I_{\rm B}$ = -20 mA ⁽⁵⁾			-1.00	
Small Signa	al Characteristics					
f _T	Current Gain - Bandwidth Product	$V_{CE} = -20 \text{ V}, I_{C} = -20 \text{ mA},$		250		MHz
C _{ob}	Output Capacitance	V _{CB} = -10 V, f = -1.0 MHz			6.0	pF
NF	Noise Figure	$ I_C = -100 \ \mu A, \ V_{CE} = -5.0 \ V, \\ R_G = 2.0 \ k\Omega, \ f = 1.0 \ kHz $			4.0	dB

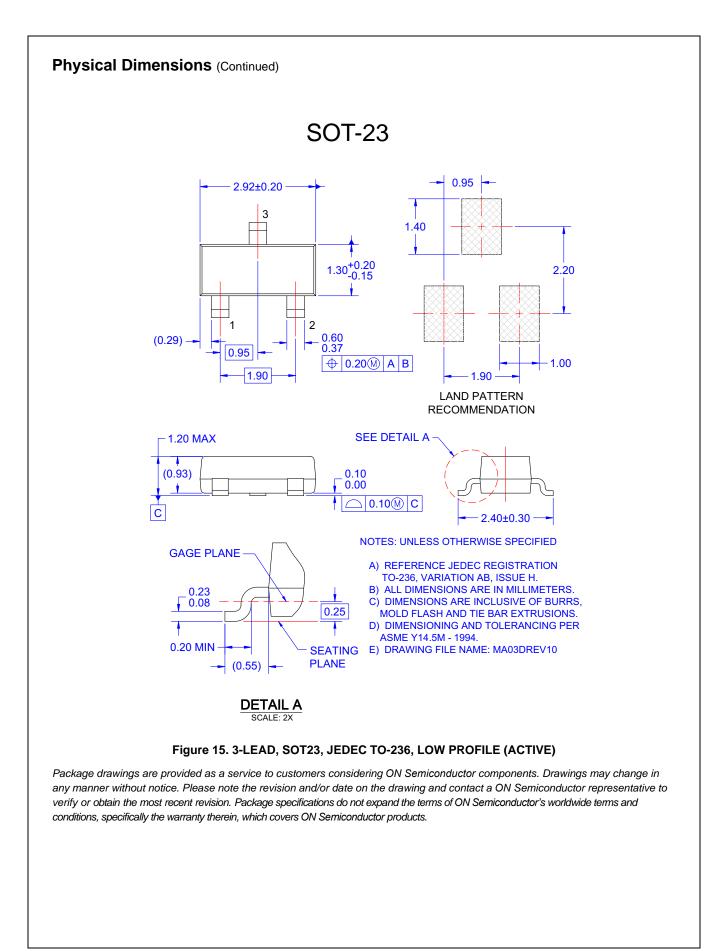
Note:

5. Pulse test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2.0%.









PN200A / MMBT200 — PNP General-Purpose Amplifier

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has negligent regarding the design or manufacture of the pars. Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an E

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Semiconductor Components Industries, LLC